

Fermi Glass Versus High-Temperature Superconductivity Behavior

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Abstract Very recently BaSrNiO₄ was reported to be a Fermi glass (Schilling et al. in J. Phys., Condens. Matter 21:015701, 2009). Its structure is essentially the one of K₂NiF₄ as is that of La₂CuO₄, in which the occurrence of high-temperature superconductivity (HTS) upon hole doping was first reported (Bednorz and Müller in Z. Phys. B 64:189, 1986; Adv. Chem. 100:757, 1988). The carriers in both have mainly e_g character, and move in a stochastic potential as documented by a number of experiments. The difference of the two behaviors is mainly ascribed to the formation of intersite bipolarons (Kabanov and Mihailovic in J. Supercond. 13:950, 2000), which is estimated to be up to two orders of magnitude larger in La₂CuO₄ than in BaSrNiO₄. From this it follows that for HTS to occur, a large bipolaron formation energy in layered structures is required.

Keywords Fermi glass vs. high-temperature superconductivity

The discovery of superconductivity in La_{2-x}Me_xCuO₄, with Me = Ba, Sr etc., [4, 5] led to a worldwide effort in materials science to find new doped ionic compounds with enhanced superconducting transition temperatures T_c . In one avenue of research, compounds were synthesized in which the CuO₂ planes were maintained. Others looked for entirely new layered crystals. In the former the so far highest T_c of 133.5 K at ambient pressure was found [22]. In the latter effort, the picnides were discovered, in which a maximum T_c of 56 K was reported [8, 21], still below the boiling point

of liquid nitrogen. In between these possibilities is the one in which the perovskite-type MeO₂ plane is maintained, but the Cu²⁺ ion is replaced by another transition-metal ion. The Ni³⁺ ion was a promising candidate because its low-spin configuration 3d⁷ is t_{2g}⁶, e_g¹. This means that Ni³⁺ has one Jahn–Teller e_g electron, like the Cu²⁺ ion has one e_g hole. It was known that LaSrNiO₄, in which Ni is trivalent, is a metal. However, Demazeau et al. [10] found that LaBaNiO₄ with its enlarged lattice exhibits variable range hopping (VRH). Therefore, Schilling et al. [23] more recently investigated the mixed crystal series LaSr_{1-x}Ba_xNiO₄ for the occurrence of HTS. The series starting with $x = 1$ and VRH became more conducting with decreasing x , with $x = 0$ being a metal, i.e., an Anderson transition. For BaLaNiO₄ ($x = 1$), susceptibility, specific heat, and thermal conductivity indicated a near constant electron density at the Fermi energy, which means that it is a Fermi glass as originally predicted by Anderson [2, 3].

To understand the entirely different behaviors of, say, La_{2-x}Sr_xCuO₄, i.e., when partially replacing the La³⁺ with two-valent ions, such as Sr²⁺, and BaLaNiO₄, we have to go back to the first experimental observation of a Fermi glass. This was reported for CaV₂O₅ doped with protons [19]. The electrons introduced to keep charge neutrality reduce the valency of V from 5+ to 4+, yielding a 3d¹⁺ state. For high enough dopings, the electrons become itinerant and exhibit VRH, i.e., a conductivity with a $T^{-1/4}$ dependence as reproduced in Fig. 1a.

Because of the mobile carriers one electron spin resonance (ESR) line with Lorentzian line shape is detected, which upon integration yields the paramagnetic susceptibility $\chi(T)_p$ of the carriers (multiplied by T because of the Curie law). This is reproduced in Fig. 1b. From it one sees that $\chi(T)_p$ is independent of the temperature from

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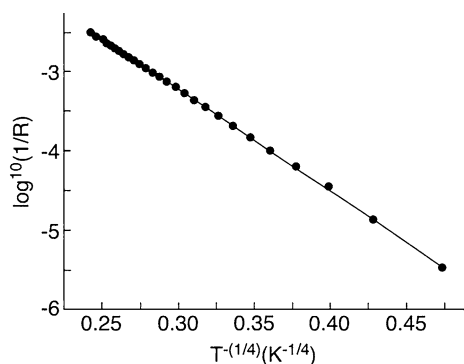


Fig. 1a The inverse resistivity plotted logarithmically as a function of $T^{-1/4}$ for a H:CaV₂O₆ sample heated for 20 h at 470 °C. $\sigma_0 = 3.95 \Omega^{-1} \text{ cm}^{-1}$ and $T_0^{1/4} = 29.7 \text{ K}^{1/4}$ [see Ref. [19]]

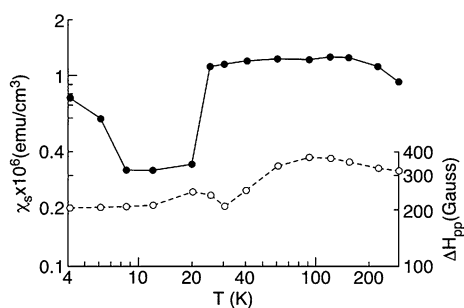


Fig. 1b Conduction-electron spin resonance line susceptibility and width of H:CaV₂O₅ as a function of $\log T$ for the same sample as in Fig. 1a. Because of macroscopic inhomogeneities, the scale of the spin susceptibility is only approximate (see Ref. [19])

300 K down to 20 K in the range where VRH is observed. This is what had been predicted for a Fermi glass by Anderson [2, 3]. Below 20 K, $\chi(T)_p$ drops to a considerably lower value. This occurred for *all* samples tested at the time, and it was commented upon in the last paragraph of [19]: *The reproducible drop in χ_p below 20 K could also result from negative electron correlation-energy of the order of 10 K, which tends to pair the electrons.*

We can now compare the Fermi-glass response found in CaV₂O₅ to that in BaLaNiO₄. In Fig. 2a, the temperature dependence of the resistivity and in Fig. 2b that of the specific heat are reproduced from [23]. Over the low temperature range where VRH is observed, $\chi(T)_p$ was not constant upon cooling but increased slightly and was analyzed by an expression $\chi(T)_p = C/(T + \Theta) + \chi_0$, with either $\Theta = 0$ or $\Theta \neq 0$. In the former, $C = 2.4 \times 10^{-2} \text{ emu K mol}^{-1}$ and $\chi_0 = 4.5 \times 10^{-4} \text{ emu mol}^{-1}$ and in the latter case $C = 5.4 \times 10^{-2} \text{ emu K mol}^{-1}$ and $\chi_0 = 3.4 \times 10^{-4} \text{ emu mol}^{-1}$, i.e., a substantial temperature-independent paramagnetic term. No drop in $\chi(T)_p$ can be seen, but at low temperatures the data scatter quite a bit. Therefore, in Fig. 2b the specific-heat data are reproduced below 16 K. In these, no clear deviation from the fit of a $C(T)/T = \beta T^2 + \gamma$ is detectable. Here the elec-

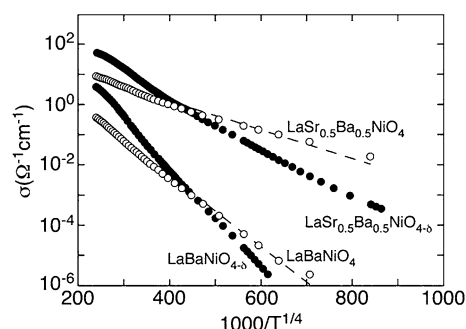


Fig. 2a Electrical conductivities σ versus $T^{-1/4}$ of as-prepared samples (full circles) and of high-pressure oxygen-annealed samples (open circles). The dashed lines are fits according to a variable-range hopping-type conductivity (see Ref. [23])

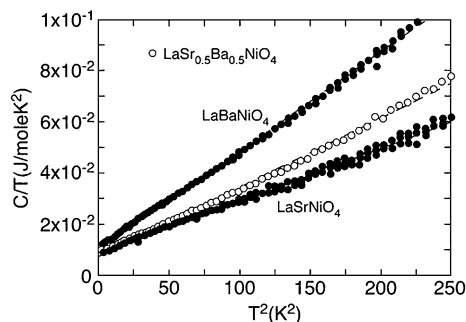


Fig. 2b Reduced specific heat C/T versus T^2 data of LaSrNiO₄ (bottom), oxygen treated LaSr_{0.5}Ba_{0.5}NiO₄ (middle) and LaBaNiO₄ (upper curve). The dashed lines are fits to $C(T) = \beta T^3 + \gamma T$ (see Ref. [23])

tronic term γ equals 9.5 mJ/mol K. Therefore, there no sign of bipolaron formation appears to be present.

This behavior has to be verified by integrating over the motionally narrowed ESR line of the Ni³⁺ as a function of temperature to obtain $\chi(T)_p$. The Ni³⁺ ESR line has been observed earlier [10]. If also in $\chi(T)_p$ no drop occurs, then the bipolaron formation energy is lower than that in H:CaV₂O₅, and in both one to two orders of magnitude lower than in the low doping range of La_{2-x}Sr_xCuO₄. In the latter compound, the electron paramagnetic resonance (EPR) of probing Mn²⁺ ions yielded a bipolaron formation energy of 460(40) K independent of doping for x from 1 to 6%, see Fig. 3 [24, 25]. A comparison of Fig. 1b, Fig. 2b and Fig. 3 indicates that for a small bipolaron formation energy a Fermi glass and for a large one HTS results. In all three cases the carrier concentration is clearly inhomogeneous, that is, metallic clusters or stripes and more isolating areas are present, as it follows from the VRH or EPR [10, 23–25].

From this experimental interpretation, the question naturally arises why the energy for bipolaron formation is about two orders of magnitude larger in La₂CuO₄ than in BaLaNiO₄. In La_{2-x}Sr_xCuO₄ there are two holes with an-

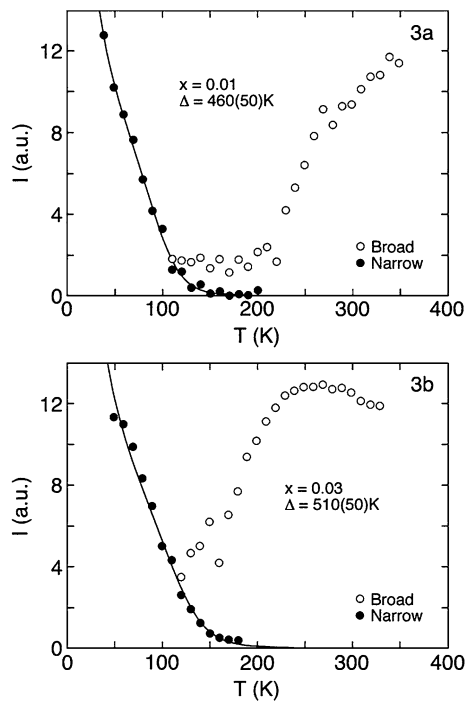


Fig. 3 Temperature dependence of the narrow and broad EPR signal intensity in $\text{La}_{2-x}\text{Sr}_x\text{Cu}_{0.98}\text{Mn}_{0.02}\text{O}_4$ with different Sr dopings: (a) $x = 0.01$; (b) $x = 0.03$. The solid lines represent fits using the model described in Ref. [24, 25]

tiparallel spin having their density mainly located on oxygens near two Cu^{2+} (with an oxygen connecting them). The trapping occurs because the oxygens surrounding these Cu^{2+} ion sites are locally shifted by a Jahn–Teller e_g conformation [15, 17]. Essential is the density of the two holes on the oxygens where calculations from first principles yielded a formation energy between 100 and 700 K [16] comparable with that of 460 K found by EPR [24, 25]. On the other hand, in BaLaNiO_4 the carriers in question are located mainly on 3d, e_g orbitals, at least at low temperatures [10]. Apart from hybridization, a spreading of these electrons onto oxygens would render the charge of the latter more negative than two. However, this is not known to occur, quite in contrast to the opposite, namely, the lowering of the oxygen charge as it occurs in hole-doped La_2CuO_4 . We believe that because of this more local charge on the Ni^{3+} in BaLaNiO_4 the bipolaron formation is hindered. Finally in proton-doped CaV_2O_6 , the energy for bipolaron formation lies in between the ones of the compounds just discussed. Here the donated electrons are mainly located at the vanadium ions, forming V^{4+} , as observed by EPR. Owing to the higher valency, the hybridization is larger than for Ni^{3+} , and a larger bipolaron energy formation appears than in BaLaNiO_3 .

The above discussion has left out the dependence of the bipolaron binding energy on the degree of doping as was first theoretically investigated by Alexandrov, Kabanov and Mott (AKM) [1]. In this important paper, AKM calculated

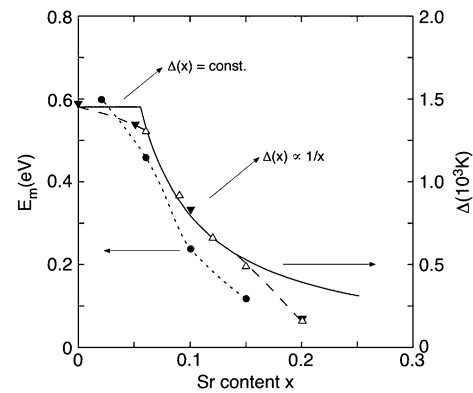


Fig. 4 Composition dependences of the bipolaron binding energy Δ and $E_m = 2g^2\hbar\omega$. The left-hand and right-hand scales are for the circle and triangle symbols, respectively. Δ is proportional to $1/x$ for $0.06 < x < 0.15$. The solid triangles represent T_{\max} as determined by Johnston [14]. The results for E_m are from reference [6]

the bipolaron binding energy as a function of the carrier concentration x , see Fig. 4. For low x , the binding energy is constant up to x_c (as observed by EPR [24, 25]), and from there it decreases as $1/x$. This was confirmed by the analysis of existing susceptibility data by Müller et al. [20]. In order to get the analysis self-consistent they added a temperature-independent Pauli term, see Fig. 4. The latter is present because of the metallic clusters found by EPR already for low dopings [24, 25]. Note also that in photoemission this was later seen as density of states at the X and M points of the Brillouin zone, i.e., Fermi arcs and bipolaron states, respectively [9]. Towards the optimum doping near $x = 0.15$, the bipolaronic binding energy is lowered by a factor of ≈ 6 , see Fig. 4. However it appears that it does not vanish. This can be concluded from the doping dependence of the pseudogap temperature T^* , where the bipolaron formation occurs upon cooling, see Fig. 13 in [18]. In contrast to theories where at optimum doping a quantum critical point exists, requiring $T^*(x)$ to vanish, $T^*(x)$ remains finite as verified by tunneling [11], inelastic neutron scattering [13], and EPR [18] measurements. Therefore, the bipolaron binding energy stays finite as well. The above addressed bipolaron binding near optimum doping at $x = 0.15$ is $\Delta \simeq 70$ K (Fig. 4), whereas in LaBaNiO_4 the concentration is $x = 1$. Here the bipolaron binding may well be nil, despite the fact that it is finite for $x \approx 0.15$. For this doping the two-band polaronic model of Bussmann-Holder and Keller [7] is more appropriate.

In [23], the reason for the occurrence of a stochastic potential in LaBaNiO_4 or, in other words, the rising of the mobility edge to the Fermi level such that VRH occurs, was not addressed. From the incomplete oxygenation of their samples, Demazeau et al. [10] argued that Ni^{2+} ions may be present. However in [23] highly oxygenated samples exhibited a very clear VRH, see Fig. 1a. What was not considered in [23] and [10] is the presence of high- and low-spin Ni^{3+}

as the origin of stochasticity due to local lattice deformation because of the different size of the high- and low-spin Ni^{3+} [12]. This is well documented in Fig. 3 of [10]. The high-spin signal reduces substantially upon cooling, and at 4.2 K is barely visible. However, it may still be responsible for the Curie law term $C = 2.4$ to $5.4 \times 10^{-2} \text{ emu K mol}^{-1}$ in the susceptibility [23], and thus warrants a detailed EPR investigation. We also note that in the normal samples of LaBaNiO_4 , VRH is less well followed (a straight line in the $T^{-1/4}$ plots) than in $\text{H:Ca}_2\text{V}_5\text{O}_4$, see Fig. 1a.

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